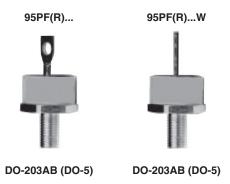


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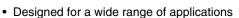
Standard Recovery Diodes Generation 2 DO-5 (Stud Version), 95 A



95 A

FEATURES

· High surge current capability





• Stud cathode and stud anode version

- · Wire version available
- · Low thermal resistance
- · UL approval pending
- Compliant to RoHS directive 2002/95/EC
- Designed and qualified for multiple level

TYPICAL APPLICATIONS

- · Battery charges
- Converters
- · Power supplies
- · Machine tool controls
- Welding

MAJOR RATINGS AND CHARACTERISTICS					
PARAMETER	TEST CONDITIONS	VALUES	UNITS		
I _{F(AV)}		95	A		
	T _C	140	°C		
I _{F(RMS)}		149	A		
I _{FSM}	50 Hz	2000	^		
	60 Hz	2090	А		
l ² t	50 Hz	20 000	A ² s		
	60 Hz	18 180			
V _{RRM}	Range	400 to 1200	V		
T _J		- 55 to 180	°C		

ELECTRICAL SPECIFICATIONS

PRODUCT SUMMARY

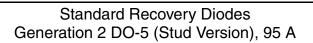
I_{F(AV)}

VOLTAGE RATINGS					
TYPE NUMBER	VOLTAGE CODE	V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} MAXIMUM AT T _J = 150 °C mA	
	40	400	500		
95PF(R)(W)	80	800	960	9	
	120	1200	1440		

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95PF(R)...(W) Series

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FORWARD CONDUCTION						
PARAMETER	SYMBOL	MBOL TEST CONDITIONS		VALUES	UNITS	
Maximum average forward current		180° conduction, half sine wave			95	Α
at case temperature		I _{F(AV)} 180° conduction, half sine wave		140	°C	
Maximum RMS forward current	I _{F(RMS)}			149	Α	
		t = 10 ms	No voltage reapplied		2000	А
Maximum peak, one cycle forward,		t = 8.3 ms			2090	
non-repetitive surge current	I _{FSM}	t = 10 ms	100 % V _{RRM} reapplied	Sinusoidal half wave,	1680	
		t = 8.3 ms			1760	
	l ² t	t = 10 ms	No voltage	initial T _J = 150 °C	20 000	- A ² s
Maximum 12t for fusing		t = 8.3 ms	reapplied		18 180	
Maximum I ² t for fusing		t = 10 ms	100 % V _{RBM}		14 100	
		t = 8.3 ms	reapplied		12 800	
Maximum I ² √t for fusing	I ² √t	t = 0.1 ms to 10 ms, no voltage reapplied			200 000	A²√s
Low level value of threshold voltage	V _{F(TO)}	(16.7 % x π x $I_{F(AV)}$ < I < π x $I_{F(AV)}$), $T_J = T_J$ maximum		0.73	V	
Low level value of forward slope resistance	r _f	(16.7 % x π x $I_{F(AV)} < I < \pi$ x $I_{F(AV)}$), $T_J = T_J$ maximum		2.4	mΩ	
Maximum forward voltage drop	V_{FM} $I_{pk} = 267 \text{ A}, T_J = 25 °C, t_p = 400 \mu s rectangular wave$		1.40	V		

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range	T_J, T_{Stg}		- 55 to 180	°C	
Maximum thermal resistance, junction to case	R_{thJC}	DC operation	0.27	K/W	
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth, flat and greased	0.25		
Maximum allowable mounting torque (+ 0 %, - 10 %)		Not lubricated thread, tighting on nut ⁽¹⁾	3.4 (30)		
		Lubricated thread, tighting on nut (1)	2.3 (20)	N · m	
		Not lubricated thread, tighting on hexagon (2)	4.2 (37)	(lbf · in)	
		Lubricated thread, tighting on hexagon (2)	3.2 (28)		
Approximate weight			15.8	g	
Approximate weight			0.56	OZ.	
Case style		See dimensions - link at the end of datasheet	DO-203AB (DO-5)		

Notes

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⁽¹⁾ Recommended for pass-through holes

⁽²⁾ Torque must be appliable only to hexagon and not to plastic structure, recommended for holed heatsink



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△R _{thJC} CONDUCTION					
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS	
180°	0.14	0.10			
120°	0.16	0.17			
90°	0.21	0.22	$T_J = T_J \text{ maximum}$	K/W	
60°	0.30	0.31			
30°	0.50	0.50			

Note

The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

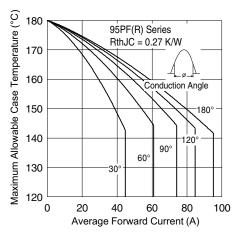


Fig. 1 - Current Ratings Characteristics

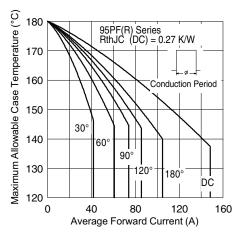


Fig. 2 - Current Ratings Characteristics

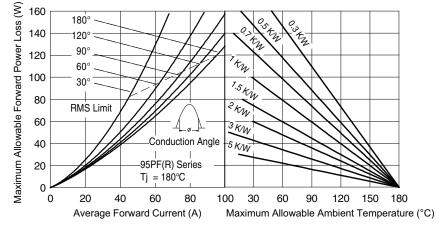


Fig. 3 - Forward Power Loss Characteristics

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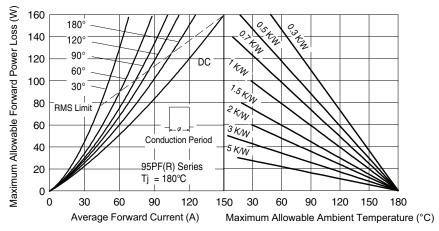


Fig. 4 - Forward Power Loss Characteristics

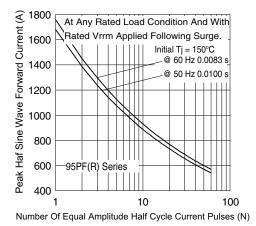


Fig. 5 - Maximum Non-Repetitive Surge Current

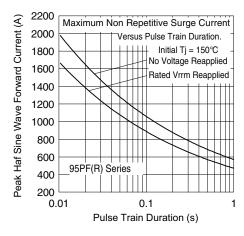


Fig. 6 - Maximum Non-Repetitive Surge Current

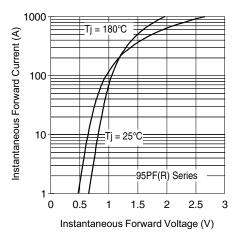


Fig. 7 - Forward Voltage Drop Characteristics

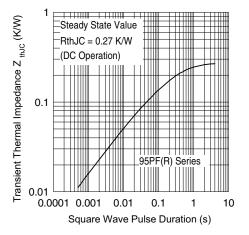


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics

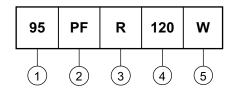


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ORDERING INFORMATION TABLE

Device code



- 1 • 95 = Standard device
 - 97 = Isolated lead on standard terminal with silicone sleeve available for 1200 V only (red = Reverse polarity)
 (blue = Normal polarity)
- PF = Plastic package
- None = Stud normal polarity (cathode to stud)
 - R = Stud reverse polarity (anode to stud)
 - Voltage code x 10 = V_{RRM} (see Voltage Ratings table)
 None = Standard terminal
 - None = Standard terminal (see dimensions for 95PF(R)... - link at the end of datasheet)
 - W = Wire terminal (see dimensions for 95PF(R)...W - link at the end of datasheet)

LINKS TO RELATED DOCUMENTS			
Dimensions	www.vishay.com/doc?95345		

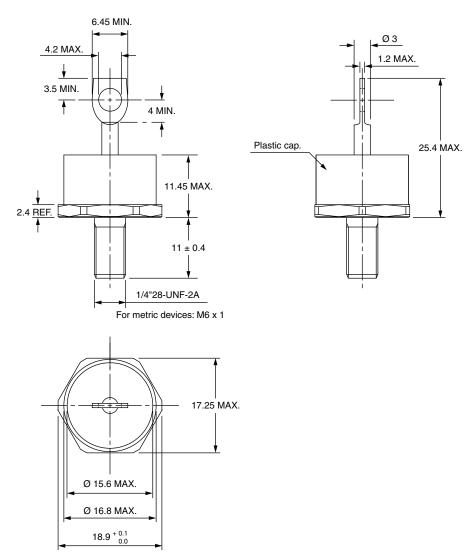
Document Number: 93532 Revision: 20-May-09



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DO-203AB (DO-5) for 50PF(R)...(W), 80PF(R)...(W) and 95PF(R)...(W) Series

DIMENSIONS FOR 80PF(R), 50PF(R) AND 95PF(R) SERIES in millimeters



Note

• For metric device please contact factory

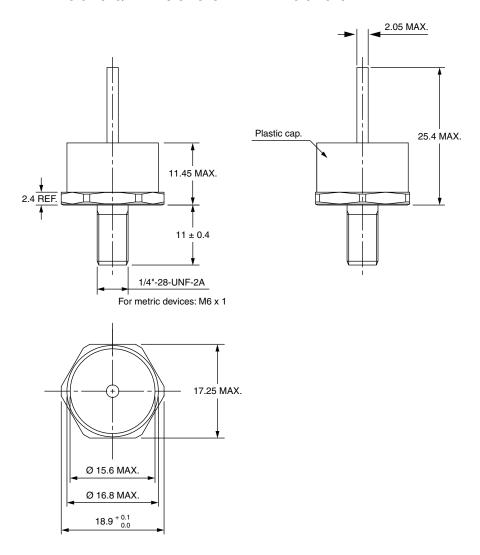
Outline Dimensions

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DO-203AB (DO-5) for 50PF(R)...(W), 80PF(R)...(W) and 95PF(R)...(W) Series



DIMENSIONS FOR 80PF(R)...(W), 50PF(R)...(W) AND 95PF(R)...(W) SERIES in millimeters



Note

• For metric device please contact factory

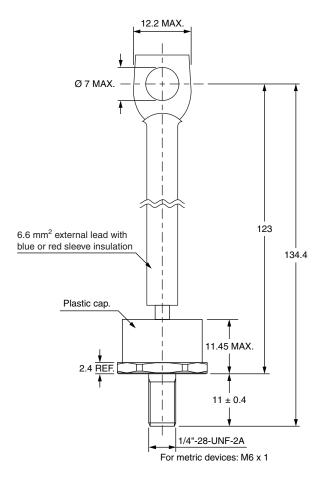
Document Number: 95345 Revision: 26-Aug-08



DO-203AB (DO-5) for 50PF(R)...(W), 80PF(R)...(W) and 95PF(R)...(W) Series

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DIMENSIONS FOR 52PF(R), 82PF(R) AND 97PF(R) SERIES in millimeters



Note

• For metric device please contact factory



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Revision: 02-Oct-12 Document Number: 91000